UVA Sensor: LD-G360-020T

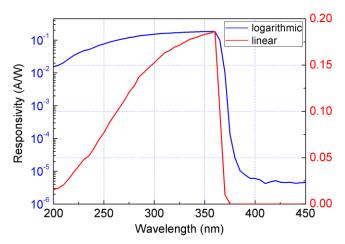


Features	Indium Gallium nitride based material	
	Broad band UVA+UVB+UVC photodiode	
	Photovoltaic mode operation	
	TO-46 metal housing	
	Good visible blindness	
	High responsivity and low dark current	
Applications	UV LED monitoring	
	UV radiation dose measurement	
	UV Curing	

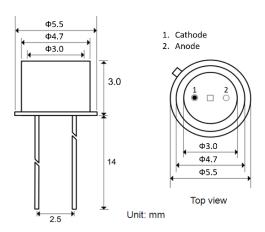
Specifications

Parameter	Symbol	Value	Unit
Spectral characteristics (25 °C)			
Wavelength of peak responsivisity	λ_{max}	360	nm
Peak responsivisity (at 360 nm)	R _{max}	0.18	A/W
Spectral response range	-	180~370	nm
UV/visible rejection ratio (R _{max} /R _{400 nm})	VB	>10 ⁴	-
General characteristics (25 °C)			
Chip size	А	0.2	mm ²
Dark current (1 V reverse bias)	١ _d	<0.1	nA
Capacitance (at 0 V and 1 MHz)	С	4.5	pF
Temperature coefficient	T _c	-0.1	%/°C
Maximum ratings			
Operation temperature range	T _{opt}	-40~85	°C
Storage temperature range	T _{stor}	-40~85	°C
Soldering temperature (3 s)	T _{sold}	260	°C
Reverse voltage	V _{Rmax}	10	V

Spectral response



Package dimensions



*Caution: ESD can damage the device hence please avoid ESD.